

Features

- High reliability
- General purpose leads
- Peak wavelength λp=940nm
- Mechanically and spectrally matched to the phototransistor
- Low forward voltage
- High radiant intensity

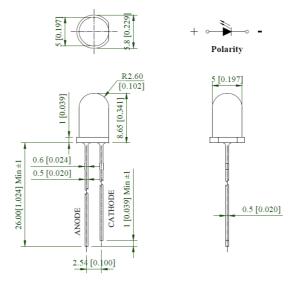
Applications

- Optoelectronic Switch
- IR Touch-Panel
- Industrial IR Equipment
- Consumer Electronics
- High Speed IR Communications

Description

- The infrared emitting diode (940nm) is a high intensity diode, molded in a water clear transparent plastic package.
- The device is spectrally matched with silicon photodiode and phototransistor.

Package Dimensions in mm



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is \pm 0.25 mm (.010 $^{\prime\prime}$) unless otherwise noted.

Figure 1. INL-5AHIR30 Package Dimensions



Absolute Maximum Rating at 25°C (Note 1)

Product	Emission Color	P _d (mW)	I _F (mA)	I _{FP} * (A)	V _R (V)	T _{OP} (°C)	T _{ST} (°C)
INL-5AHIR30	Infrared	150	100	1	5	-40°C~+80°C	-40°C~+85°C

Notes

Electrical Characteristics $T_A = 25$ °C (Note 1)

Product	Emission		V _F (V)		λ(nm)			Viewing Angle	Ee(mW/sr)	
	Color	I _F (mA)	min	max	λ_{D}	$\lambda_{ extsf{P}}$	Δλ	2 0 1/2	min	typ.
INL-5AHIR30	Infrared	20	0.8	1.5	-	940	50	30	7.8	12

Notes

1. Performance guaranteed only under conditions listed in above tables.

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection



The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AllnGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly.

If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

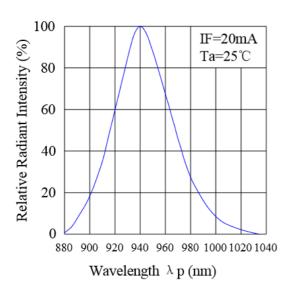
Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

^{1.} Condition for IFP is pulse of 1/10 duty and 1kHz frequency

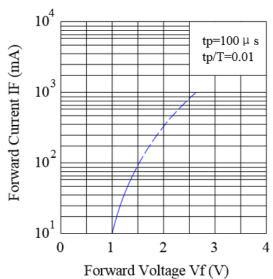


Typical Characteristic Curves

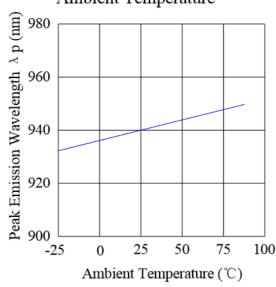
Spectral Distribution



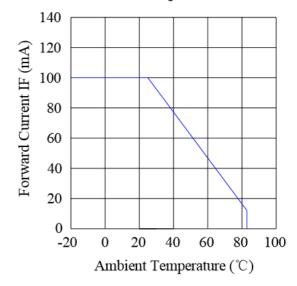
Forward Current & Forward Voltage



Peak Emission Wavelength & Ambient Temperature

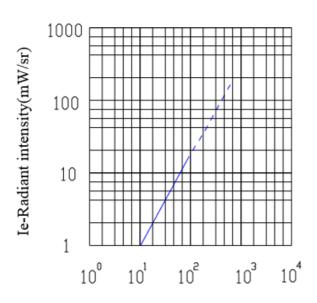


Forward Current & Ambient Temperature



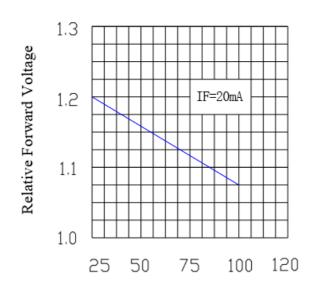






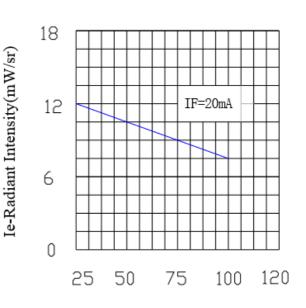
IF-Forward Current(mA)

Forward Voltage & Ambient Temperature(°C)



Ambient Temperature (°C)

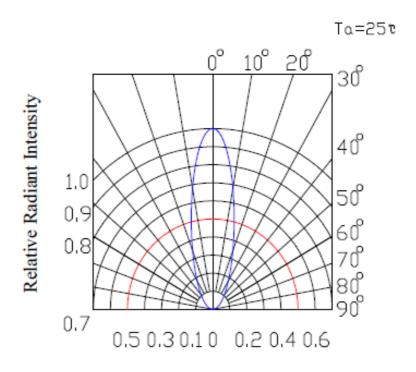
Relative Intensity & Ambient Temperature(°C)



Ambient Temperature (°C)



Typical Characteristic Curves – Radiation Pattern

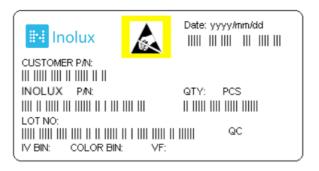


Ordering Information

Product	Emission Color	Technology	Test Current I _F (mA)	Radiant Intensity Ee (mW/sr) (Typ.)	Forward Voltage V _F (V) (Typ.)	Orderable Part Number
INL-5AHIR30	Infrared	AlGaAs	20	10	1.2	INL-5AHIR30



Label Specifications



Inolux P/N:

1	N	L	-	5	А	-	HIR	3	0		Х	Х	Х	Х
				Package		Lens	Color	Viev	View Angle			Customized Stamp-off		
	Inolu mp T			stan	A = dard nm	(Blank) = clear	HIR = 940nm	30 =	30 deg.					

Lot No.:

Z	2	0	1	7	01	24	001
Internal		Voor (2017	2019 \	Month	Data	Corial	
Tracker		Year (2017	, 2010,)	WIOTILIT	Date	Serial	





Reliability

Item	Frequency/ lots/ samples/ failures	Standards Reference	Conditions				
Precondition	For all reliability monitoring tests according to JEDEC Level 2	J-STD-020	1.) Baking at 85°C for 24hrs2.) Moisture storage at 85°C/60% R.H. for 168hrs				
Solderability	1Q/ 1/ 22/ 0	JESD22-B102-B And CNS-5068	Accelerated aging 155°C/ 24hrs Tinning speed: 2.5+0.5cm/s Tinning: A: 215°C/ 3+1s or B: 260°C/ 10+1s				
Resistance to soldering heat	Dipping soldering terminal only Soldering bath temperature A: 260+/-5°C; 10+/-1s B: 350+/-10°C; 3+/-0.5s						
Operating life test	1Q/ 1/ 40/ 0	CNS-11829	1.) Precondition: 85°C baking for 24hrs 85°C/ 60%R.H. for 168hrs 2.) Tamb25°C; IF=20mA; duration 1000hrs				
High humidity, high temperature bias	1Q/ 1/ 45/ 0	JESD-A101-B	Tamb: 85°C Humidity: 85% R.H., IF=5mA Duration: 1000hrs				
High temperature bias	1Q/ 1/ 20	IN specs.	Tamb: 55°C IF=20mA Duration: 1000hrs				
Pulse life test	1Q/ 1/ 40/ 0		Tamb25°C, If=20mA,, Ip=100mA, Duty cycle=0.125 (tp=125 μ s,T=1sec) Duration 500hrs)				
Temperature cycle	1Q/ 1/ 76/ 0	JESD-A104-A IEC 68-2-14, Nb	A cycle: -40 degree C 15min; +85 degree C 15min Thermal steady within 5 min 300 cycles 2 chamber/ Air-to-air type				
High humidity storage test	1Q/ 1/ 40/ 0	CNS-6117	60+3°C 90+5/-10% R.H. for 500hrs				
High temperature storage test	1Q/ 1/ 40/ 0	CNS-554	100+10°C for 500hrs				
Low temperature storage test	1Q/ 1/ 40/ 0	CNS-6118	-40+5°C for 500hrs				





Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	01-19-2019
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Mouser Electronics

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